NSN 5962-01-357-6611

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-357-6611

Body Length: 1.280 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.140 inches and 0.185 inches **Maximum Power Dissipation Rating:** 1.2 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and monolithic and positive outputs **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input **Case Outline Source And Designator:** D-9 mil-m-38510 **Current Rating Per Characteristic:** 100.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Product Name:** And-or invert gate array Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source Memory Device Type: Pal **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a Unit Of Measure:

NSN 5962-01-357-6611

Memory Microcircuit - Page 2 of 2

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

